

## Low-Voltage 3.5Ω, SPDT, CMOS Analog Switches

#### **General Description**

The MAX4729/MAX4730 single-pole/double-throw (SPDT) switches operate from a single supply ranging from +1.8V to +5.5V. These switches provide low  $3.5\Omega$  on-resistance (RoN), as well as  $0.45\Omega$  RoN flatness with a +2.7V supply. These devices typically consume only 1nA of supply current, making them ideal for use in low-power, portable applications. The MAX4729/MAX4730 feature low-leakage currents over the extended temperature range, TTL/CMOS-compatible digital logic, and excellent AC characteristics.

The MAX4729/MAX4730 are available in small 6-pin SC70 and 6-pin  $\mu$ DFN packages. The MAX4729/MAX4730 are offered in three pinout configurations to ease design. The MAX4729/MAX4730 are specified over the extended -40°C to +85°C temperature range.

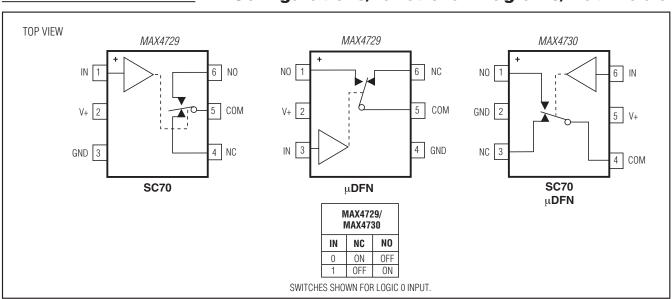
#### **Applications**

Battery-Operated Equipment
Audio and Video-Signal Routing
Low-Voltage Data-Acquisition Systems
Sample-and-Hold Circuits
Communications Circuits
Relay Replacement

#### \_ Features

- ♦ Low 3.5Ω Ron (+2.7V Supply)
- ♦ 0.45Ω Ron Flatness (+2.7V Supply)
- ♦ 0.05Ω Ron Match Between Channels (+2.7V Supply)
- ♦ Tiny SC70 and µDFN Packages
- ♦ -3dB Bandwidth: 300MHz
- ♦ Low On-Capacitance: 19.5pF
- ♦ 0.036% Total Harmonic Distortion
- ♦ Low Supply Current: 1nA
- ♦ +1.8V to +5.5V Single-Supply Operation

#### Pin Configurations/Functional Diagrams/Truth Table



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#### **ABSOLUTE MAXIMUM RATINGS**

(All voltages referenced to ground.)	
V+, IN	0.3V to +6V
COM, NO, NC (Note 1)	
Continuous Current (IN, V+, GND)	±30mA
Continuous Current (COM, NO, NC)	
Peak Current COM, NO, NC	
(Pulsed at 1ms, 10% Duty Cycle)	±150mA

Continuous Power Dissipation ( $T_A = +70^{\circ}C$ )	
μDFN (derate 2.1mW/°C above +70°C)	
SC70 (derate 3.1mW/°C above +70°C)	245mW
Operating Temperature Range	40°C to +85°C
Maximum Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C
Soldering Temperature (reflow)	+260°C

**Note 1:** Signals on NO, NC, or COM exceeding V+ or GND are clamped by internal diodes. Signals on IN exceeding GND are clamped by an internal diode. Limit forward-diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### **ELECTRICAL CHARACTERISTICS**

 $(V+=+2.7V \text{ to } +3.6V, V_{IH}=+2.0V, V_{IL}=+0.4V, T_A=-40^{\circ}C \text{ to } +85^{\circ}C, \text{ unless otherwise noted.}$  Typical values are at  $T_A=+25^{\circ}C.$ ) (Note 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS	
ANALOG SWITCH	ANALOG SWITCH							
Analog Signal Range	V <sub>COM</sub> , V <sub>NO,</sub> V <sub>NC</sub>			0		V+	V	
On-Resistance (Note 6)	Ron	V+ = 2.7V, I <sub>COM</sub> = 10mA,	T <sub>A</sub> = +25°C		3.5	5.5	Ω	
On-nesistance (Note o)	TION	$V_{NO}$ or $V_{NC} = 0V$ to $V+$	$T_A = -40^{\circ}\text{C to } +85$			5.7	22	
		$V+ = 2.7V$ , $I_{COM} = 10mA$ , $V_{NO}$ or $V_{NC} = 0.7V$ , 1.2V, 2V	T <sub>A</sub> = +25°C		0.05	0.15		
On-Resistance Match Between Channels	A.D.o.	(MAX4729)	$T_A = -40^{\circ}C \text{ to } +85$			0.2	Ω	
(Notes 3, 6)	ΔR <sub>ON</sub>	$V + = 2.7V$ , $I_{COM} = 10mA$ ,	T <sub>A</sub> = +25°C		0.2	0.34		
		$V_{NO}$ or $V_{NC} = 0.7V$ , 1.2V, 2V (MAX4730)	$T_A = -40^{\circ}C \text{ to } +85$			0.37		
	R <sub>FLAT</sub> (ON)	V+ = 2.7V, I <sub>COM</sub> = 10mA, V <sub>NO</sub> or V <sub>NC</sub> = 0.7V, 1.2V, 2V (MAX4729)	T <sub>A</sub> = +25°C		0.8	1.5	Ω	
On-Resistance Flatness (Note 4)			$T_A = -40^{\circ}C \text{ to } +85$			2.2		
		V+ = 2.7V, I <sub>COM</sub> = 10mA, V <sub>NO</sub> or V <sub>NC</sub> = 0.7V, 1.2V, 2V (MAX4730)	T <sub>A</sub> = +25°C		0.45	0.95		
			$T_A = -40^{\circ}C \text{ to } +85$			1.3		
NO, NC Off-Leakage	INO (OFF),	V+ = 3.3V, V <sub>COM</sub> = 1V, 3V,	T <sub>A</sub> = +25°C	-2	+0.01	+2	nA	
Current	INC (OFF)	$V_{NO}$ or $V_{NC} = 3V$ , 1V	$T_A = -40^{\circ}C \text{ to } +85$	-3		+3		
COM On-Leakage Current	ICOM (ON)	$V+ = 3.3V$ , $V_{COM} = 1V$ or 3V, $V_{NO}$ or $V_{NC} = 1V$ , 3V, or float	T <sub>A</sub> = +25°C	-3	+0.01	+3	nA	
			$T_A = -40^{\circ}C \text{ to } +85$	-4		+4		
DIGITAL INPUTS								
Input Logic High	VIH		$T_A = -40^{\circ}C \text{ to } +85$	2.0			V	
Input Logic Low	VIL		$T_A = -40^{\circ}C \text{ to } +85$			0.4	V	
Input Leakage Current	I <sub>IN</sub>	V <sub>IN</sub> = 0V or 3.6V	$T_A = -40^{\circ}C \text{ to } +85$	-1	+0.005	+1	μΑ	

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#### **ELECTRICAL CHARACTERISTICS (continued)**

 $(V+=+2.7V \text{ to } +3.6V, V_{IH}=+2.0V, V_{IL}=+0.4V, T_A=-40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}, \text{ unless otherwise noted.}$  Typical values are at  $T_A=+25^{\circ}\text{C}.)$  (Note 2)

PARAMETER	SYMBOL	CONDITIONS TA		MIN	TYP	MAX	UNITS	
DYNAMIC							•	
T 0 T (N + 5)		$V_{NO}$ , $V_{NC} = 2V$ , $R_L = 300\Omega$ ,	T <sub>A</sub> = +25°C		18	45		
Turn-On Time (Note 5)	ton	C <sub>L</sub> = 35pF, Figure 1	$T_A = -40^{\circ}C \text{ to } +85$			45	ns	
Turn-Off Time (Note 5)		$V_{NO}$ , $V_{NC} = 2V$ , $R_L = 300\Omega$ ,	T <sub>A</sub> = +25°C		10	26		
rum-on time (Note 5)	toff	C <sub>L</sub> = 35pF, Figure 1	$T_A = -40^{\circ}C \text{ to } +85$			26	ns	
Break-Before-Make (Note 5)		$V_{NO}$ , $V_{NC} = 2V$ , $R_L = 300\Omega$ ,	$T_A = +25^{\circ}C$		5		ns	
break-before-Make (Note 3)		C <sub>L</sub> = 35pF, Figure 1	$T_A = -40^{\circ}C \text{ to } +85$	1				
Charge Injection	Q	V <sub>GEN</sub> = 0V, R <sub>GEN</sub> = 0, C <sub>L</sub> = 1	.0nF, Figure 3		3		рС	
NO, NC Off-Capacitance	C <sub>NO(OFF)</sub> , C <sub>NC(OFF)</sub>	f = 1MHz, Figure 4		6.5		pF		
Switch On-Capacitance	Con	f = 1MHz, Figure 4	f = 1MHz, Figure 4				рF	
Off Inclotion (Note 7)	V <sub>ISO</sub>	V <sub>NO</sub> = V <sub>NC</sub> = 1V <sub>RMS</sub> , R <sub>L</sub> =	f = 1MHz		-67		dB	
Off-Isolation (Note 7)		$50\Omega$ , C <sub>L</sub> = 5pF, Figure 2	f = 10MHz		-45			
On-Channel Bandwidth -3dB	BW	Signal = 0dBm, $50\Omega$ in and o	Signal = 0dBm, $50\Omega$ in and out, Figure 2		300		MHz	
Crosstalk (Note 8)	\/	NO or NC = 1V <sub>RMS</sub> , C <sub>L</sub> =	f = 1MHz		-67		dB	
Crossiaik (Note 6)	V <sub>CT</sub>	5pF, $R_L = 50\Omega$ , Figure 2	F, $R_L = 50\Omega$ , Figure 2 $f = 10MHz$		-52			
Total Harmonic Distortion	THD	$R_L = 600\Omega$ , $V_{NC}$ or $V_{NO} =$ $2V_{P-P}$ , $f = 20Hz$ to $20kHz$ +25°C			0.035		%	
POWER SUPPLY								
Power-Supply Range	V+			1.8	•	5.5	V	
Popitivo Supply Current	l+	\\. E E\\ \\\. \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\	T <sub>A</sub> = +25°C		0.001			
Positive Supply Current		$V + = 5.5V$ , $V_{IN} = 0V$ or $5.5V$	$T_A = -40^{\circ}C \text{ to } +85$			1	μΑ	

Note 2: SC70 and  $\mu$ DFN parts are 100% tested at T<sub>A</sub> = +25°C. Limits across the full-temperature range are guaranteed by design and correlation.

**Note 3:**  $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$ .

**Note 4:** RoN flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.

Note 5: Guaranteed by design.

**Note 6:** µDFN is guaranteed by design.

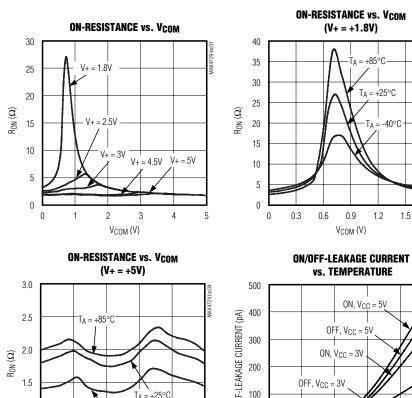
Note 7: Off-Isolation = 20log10 (VO / VI), where VO is  $V_{COM}$  and VI is either  $V_{NC}$  or  $V_{NO}$  from the network analyzer.

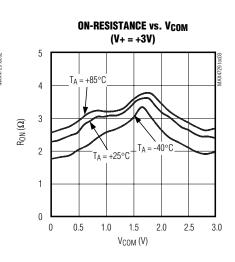
Note 8: Crosstalk is measured between the two switches.

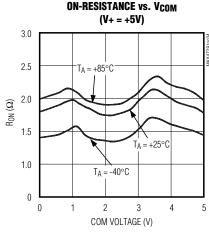
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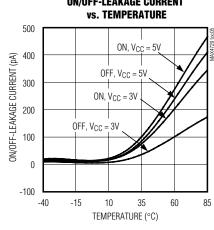
#### **Typical Operating Characteristics**

 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$ 

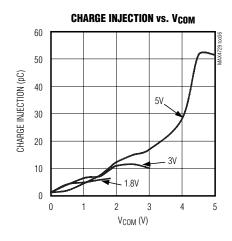


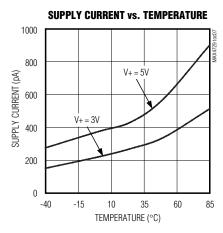


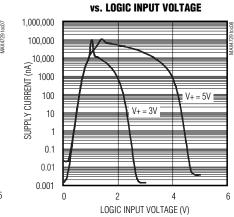


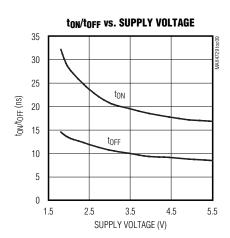


**SUPPLY CURRENT** 





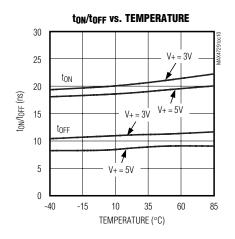


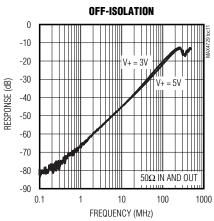


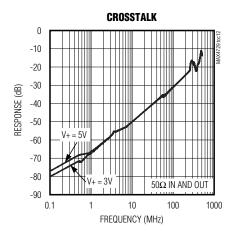
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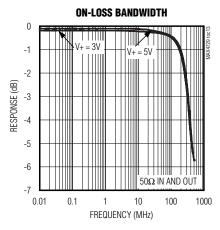
#### Typical Operating Characteristics (continued)

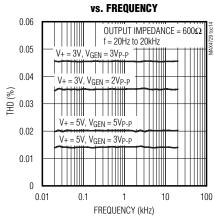
 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$ 



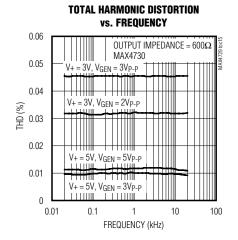








**TOTAL HARMONIC DISTORTION** 



#### **Pin Description**

	PIN			FUNCTION	
MAX	4729	MAX4730	NAME		
SC70	μDFN	SC70/µDFN			
1	3	6	IN	Logic-Control Input	
2	2	5	V+	Positive Supply Voltage	
3	4	2	GND	Ground	
4	6	3	NC	Analog Switch Normally Closed Terminal	
5	5	4	COM	Analog Switch Common Terminal	
6	1	1	NO	Analog Switch Normally Open Terminal	

## Low-Voltage 3.5 $\Omega$ , SPDT, CMOS Analog Switches

#### **Detailed Description**

The MAX4729/MAX4730 single-pole/double-throw (SPDT) switches operate from a single supply ranging from +1.8V to +5.5V. These switches provide low  $3.5\Omega$  on-resistance (RoN), as well as  $0.45\Omega$  RoN flatness with a 2.7V supply. These devices typically consume only 1nA of supply current, making them suitable for use in low-power, portable applications. The MAX4729/MAX4730 feature low-leakage currents over the entire temperature range, TTL/CMOS-compatible digital logic, and excellent AC characteristics.

#### Applications Information

#### **Digital Control Inputs**

The MAX4729/MAX4730 logic inputs accept up to +5.5V, regardless of supply voltage. For example, with a +3.3V

supply, IN can be driven low to GND and high to +5.5V, allowing for mixing of logic levels in a system. With a 2.7V to 3.6V power-supply voltage range, the logic thresholds are set so  $V_{IL} = 0.4V$  (max) and  $V_{IH} = 2V$  (min).

## Power-Supply Sequencing and Overvoltage Protection

**Caution:** Do not exceed the absolute maximum ratings because stresses beyond the listed ratings can cause permanent damage to the device. Proper power-supply sequencing is recommended for all CMOS devices. Always apply V+ before applying analog signals, especially if the analog signal is not current limited.

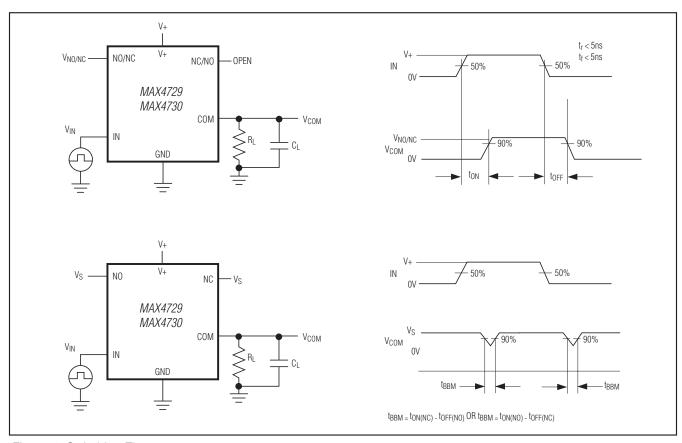


Figure 1. Switching Times

## Low-Voltage 3.5 $\Omega$ , SPDT, CMOS Analog Switches

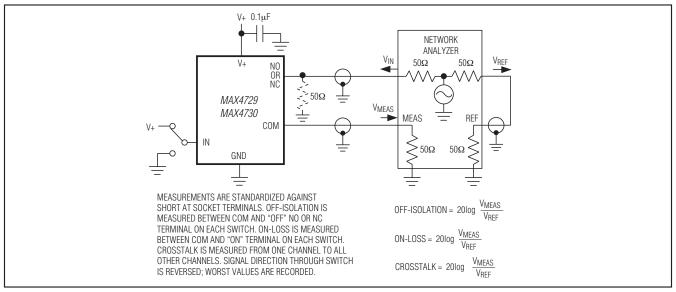


Figure 2. Off-Isolation/On-Loss Bandwidth, Crosstalk

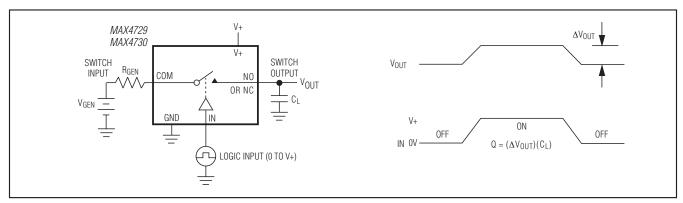


Figure 3. Charge Injection

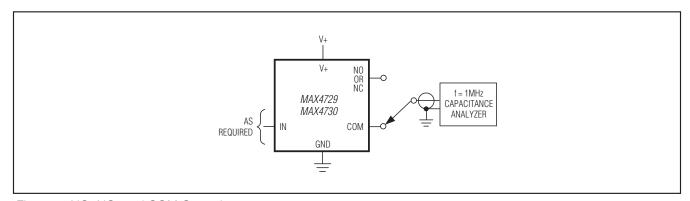


Figure 4. NO, NC, and COM Capacitance

## Low-Voltage 3.5 $\Omega$ , SPDT, CMOS Analog Switches

\_\_\_Chip Information

PROCESS: CMOS

#### **Ordering Information**

PART	TEMP RANGE	PIN-PACKAGE
MAX4729EXT+T	-40°C to +85°C	6 SC70
MAX4729ELT+T	-40°C to +85°C	6 µDFN
MAX4730EXT+T	-40°C to +85°C	6 SC70
MAX4730ELT+T	-40°C to +85°C	6 μDFN

<sup>+</sup>Denotes lead(Pb)-free/RoHS-compliant package.

#### \_Package Information

For the latest package outline information and land patterns (footprints), go to <a href="https://www.maximintegrated.com/packages">www.maximintegrated.com/packages</a>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
6 SC70	X6SN+1	21-0077	<u>90-0189</u>
6 µDFN	L611+1	21-0147	90-0080

## Low-Voltage 3.5 $\Omega$ , SPDT, CMOS Analog Switches

#### **Revision History**

REVISION	REVISION	DESCRIPTION	PAGES
NUMBER	DATE		CHANGED
2	6/14	ELT+ production status corrected	



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